

#### Class AB Stereo Headphone Driver

#### **Features**

- Operating Voltage
  - Single Supply, 3V to 6V
  - Dual Supply,  $\pm 1.5 V$  to  $\pm 3.0 V$
- · High Signal-to-Noise Ratio, 100dB
- · Low Distortion, -65dB
- Large Output Voltage Swing
- · Excellent Power Supply Ripple Rejection
- · Low Power Consumption
- · Short-Circuit Elimination
- · Wide Temperature Range
- No Switch ON/OFF Clicks
- Available in 8 pin SOP or DIP Packages
- Lead Free and Green Devices Available (RoHS Compliant)

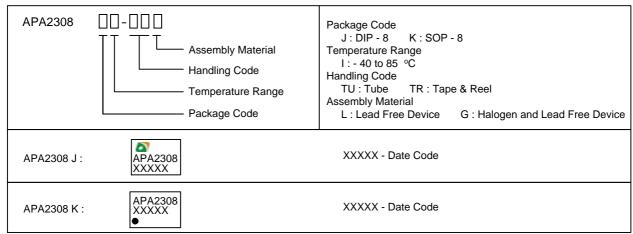
#### **Gereral Description**

The APA2308 is an integrated class AB stereo headphone driver contained in an SOP-8 and a DIP-8 plastic packages. The APA2308 is capable of delivering 280mW of max. Output power to an  $8\Omega$  load or 110mW to a  $32\Omega$  load with less than 10% (THD+N) from a 5V power supply. The device is fabricated in a CMOS process and has been primarily developed for portable digital audio applications.

#### **Applications**

· Portable Digital Audio

### **Ordering and Marking Information**



Note: ANPEC lead-free products contain molding compounds/die attach materials and 100% matte tin plate termination finish; which are fully compliant with RoHS. ANPEC lead-free products meet or exceed the lead-free requirements of IPC/JEDEC J-STD-020C for MSL classification at lead-free peak reflow temperature. ANPEC defines "Green" to mean lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500ppm by weight).

ANPEC reserves the right to make changes to improve reliability or manufacturability without notice, and advise customers to obtain the latest version of relevant information to verify before placing orders.



# **Absolute Maximum Ratings**

Symbol	Parameter	Rating	Unit
V <sub>DD</sub>	Supply Voltage	7	V
T <sub>SC(O)</sub>	Output Short-Circuit Duration, at T <sub>A</sub> =25°C, P <sub>TOT</sub> =1W	20	S
T <sub>A</sub>	Operating Ambient Temperature Range	-40 to 85	°C
T <sub>J</sub>	Maximum Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
T <sub>S</sub>	Maximum Lead Soldering Temperature, 10 Seconds	260	°C

#### **Thermal Characteristics**

Symbol	Parameter	Typical Value	Unit
	Thermal Resistance from Junction to Ambient in Free Air (Note 1)		
$\theta_{JA}$	DIP-8	109	°C/W
	SOP-8	210	

Note 1:  $\theta_{JA}$  is measured with the component mounted on a high effective thermal conductivity test board in free air.

### **Electrical Characteristics**

 $\rm V_{DD}\!\!=\!\!5V$  ,  $\rm V_{SS}\!\!=\!\!0V$  ,  $\rm T_{A}\!\!=\!\!25^{\circ}C$  ,  $\rm f_{i}\!\!=\!\!1kHz$  ,  $\rm R_{L}\!\!=\!\!32\Omega$  ( unless otherwise noted)

0	B	Dozomotov Toot Conditions		APA2308	,	1114
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
SUPPLY	•			•	•	
	Supply Voltage		-	-	-	
$V_{DD}$	Single		3.0	5.0	6.0	V
	Dual		±1.5	±2.5	±3.0	
V <sub>SS</sub>	Negative Supply Voltage		-1.5	-2.5	-3.0	V
I <sub>DD</sub>	Supply Current	No Load	-	2.5	5	mA
P <sub>TOT</sub>	Total Power Dissipation	No Load	-	12.5	25	mW
DC CHARAC	TERISTICS		•	-	,	
V <sub>I(OS)</sub>	Input Offset Voltage		-	5	-	mV
I <sub>BIAS</sub>	Input Bias Current		-	10	-	pA
V <sub>CM</sub>	Common Mode Voltage		0	-	3.5	V
$G_{V}$	Open-loop Voltage Gain	$R_L=5k\Omega$	-	75	-	dB
Io	Maximum Output Current	THD+N<0.1%	-	140	-	mA
Ro	Output Resistance		-	0.25	-	Ω
AC CHARAC	TERISTICS					
\/	0	R <sub>L</sub> =32Ω <sup>(Note 2)</sup>	0.25	-	4.75	.,,
Vo	Output Voltage Swing	R <sub>L</sub> =16Ω <sup>(Note 2)</sup>	0.5	-	4.5	V
PSRR	Power Supply Rejection Ratio	$F_i$ =100Hz $V_{RIPPLE(P-P)}$ =100mV	-	65	-	dB



### **Electrical Characteristics (Cont.)**

 $V_{DD}$ =5V ,  $V_{SS}$ =0V ,  $T_A$ =25°C ,  $f_i$ =1kHz ,  $R_i$ =32 $\Omega$  ( unless otherwise noted)

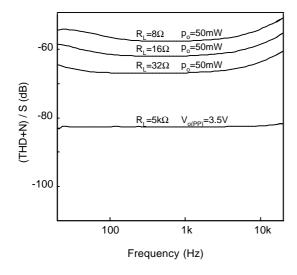
Complete	D	Took Conditions		APA2308			
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit	
AC CHARACT	TERISTICS (CONT.)						
Crosstalk	Channel Separation	$R_L=32\Omega$	-	95	-	dB	
C <sub>L</sub>	Load Capacitance		-	-	200	pF	
(THD+N)/S	Total Harmonic Distortion Plus Noise to	R <sub>L</sub> =32Ω <sup>(Note 3)</sup>	-	-65	-60	dB	
(THD+N)/S	Signal Ratio	K[=3212	-	0.05	0.1	%	
S/N	Signal to Noise Ratio		90	100	-	dB	
F <sub>G</sub>	Unity Gain Frequency	$R_L=5k\Omega$	-	5	-	MHz	
Po	Maximum Output Power	THD+N<0.1%	-	84	-	mW	
Cı	Input Capacitance		-	3	-	pF	
В	Power Bandwidth	Unity Gain Inverting	-	20	-	kHz	

Note 2 : Values are proportional to  $V_{DD}$  ; THD+N< 0.1%

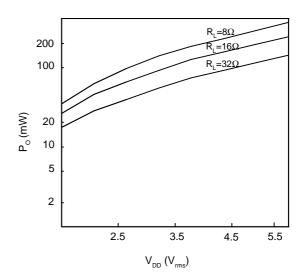
Note 3 :  $V_{DD}$ =5.0V ;  $V_{O(P-P)}$ =3.5V (at 0 dB)

# **Typical Operating Characteristics**

#### Total Harmonic Distortion Plus Noise-to-Signal Ratio as a Function of Input Frequency



# Output Power as a Function of Supply Voltage





# **Typical Operating Characteristics (Cont.)**

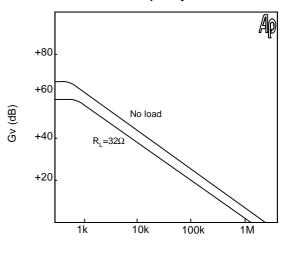
#### Crosstalk as a Function of Input

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Frequency (Hz)

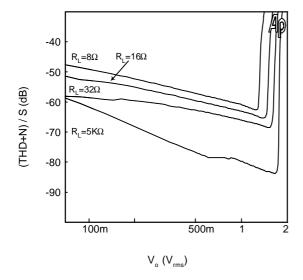
#### Open Loop Gain as a Function of Input





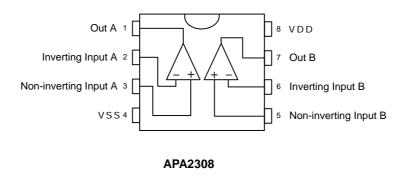
Frequency (Hz)

#### Total Harmonic Distortion Plus Noise-to-Signal Ratio as a Function of output Voltage

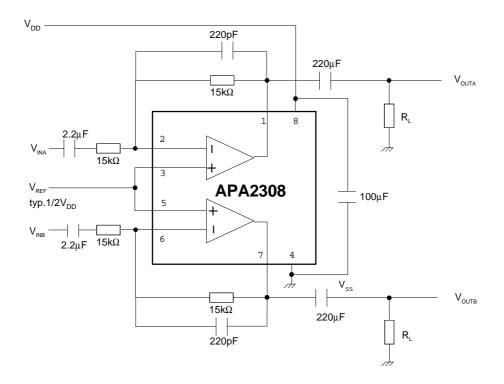




# **Block Diagram**



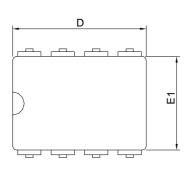
# **Typical Application Circuit**

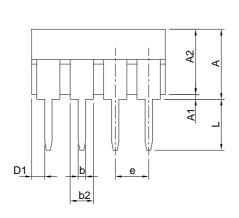


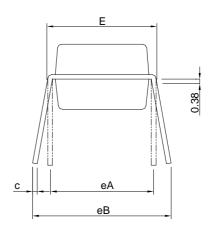


# Package Information

DIP-8





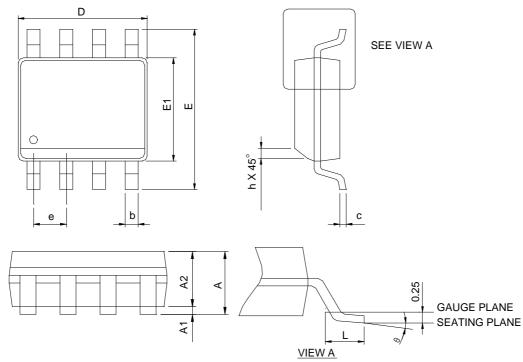


Ş		DI	P-8	
SYMBOL	MILLIM	ETERS	INC	HES
2	MIN.	MAX.	MIN.	MAX.
Α		5.33		0.210
A1	0.38		0.015	
A2	2.92	4.95	0.115	0.195
b	0.36	0.56	0.014	0.022
b2	1.14	1.78	0.045	0.070
С	0.20	0.35	0.008	0.014
D	9.01	10.16	0.355	0.400
D1	0.13		0.005	
Е	7.62	8.26	0.300	0.325
E1	6.10	7.11	0.240	0.280
е	2.54	BSC	0.100 BSC	
eA	7.62	2 BSC 0.300		) BSC
eВ		10.92		0.430
L	2.92	3.81	0.115	0.150



# **Package Information**

#### SOP-8



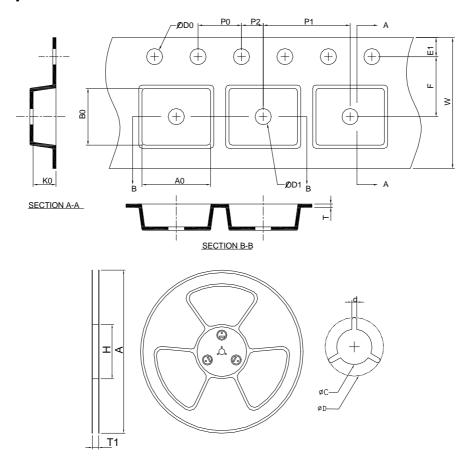
Ş		S	OP-8	
SYMBOL	MILLIM	ETERS	INC	HES
l C	MIN.	MAX.	MIN.	MAX.
Α		1.75		0.069
A1	0.10	0.25	0.004	0.010
A2	1.25		0.049	
b	0.31	0.51	0.012	0.020
С	0.17	0.25	0.007	0.010
D	4.80	5.00	0.189	0.197
Е	5.80	6.20	0.228	0.244
E1	3.80	4.00	0.150	0.157
е	1.27	.27 BSC 0.05		D BSC
h	0.25	0.50	0.010	0.020
L	0.40	1.27	0.016	0.050
θ	0°	8°	0°	8°

Note: 1. Follow JEDEC MS-012 AA.

- 2. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 6 mil per side.
- 3. Dimension "E" does not include inter-lead flash or protrusions. Inter-lead flash and protrusions shall not exceed 10 mil per side.



# **Carrier Tape & Reel Dimensions**



Application	Α	Н	T1	С	d	D	w	E1	F
	330.0 €.00	50 MIN.	12.4+2.00 -0.00	13.0+0.50 -0.20	1.5 MIN.	20.2 MIN.	12.0 ±0.30	1.75 ±0.10	5.5 ±0.05
SOP-8	P0	P1	P2	D0	D1	Т	A0	В0	K0
	4.0 <b>±</b> 0.10	8.0 <b>±</b> 0.10	2.0 <b>±</b> 0.05	1.5+0.10 -0.00	1.5 MIN.	0.6+0.00 -0.40	6.40 ±0.20	5.20 <b>±</b> 0.20	2.10 ±0.20

(mm)

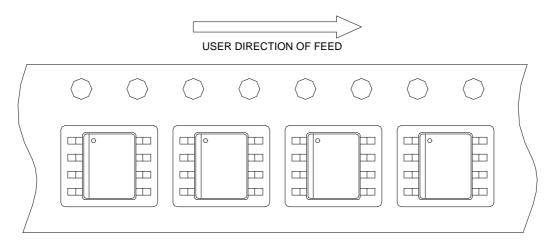
### **Devices Per Unit**

Package Type	Unit	Quantity
SOP-8	Tape & Reel	2500

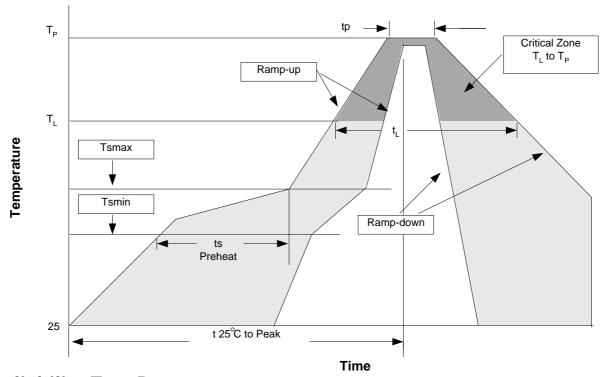


# **Taping Direction Information**

SOP-8



### Reflow Condition (IR/Convection or VPR Reflow)



# **Reliability Test Program**

Test item	Method	Description
SOLDERABILITY	MIL-STD-883D-2003	245°C, 5 sec
HOLT	MIL-STD-883D-1005.7	1000 Hrs Bias @125°C
PCT	JESD-22-B,A102	168 Hrs, 100%RH, 121°C
TST	MIL-STD-883D-1011.9	-65°C~150°C, 200 Cycles
ESD	MIL-STD-883D-3015.7	VHBM > 2KV, VMM > 200V
Latch-Up	JESD 78	10ms, 1 <sub>tr</sub> > 100mA



#### **Classification Reflow Profiles**

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate $(T_L \text{ to } T_P)$	3°C/second max.	3°C/second max.
Preheat - Temperature Min (Tsmin) - Temperature Max (Tsmax) - Time (min to max) (ts)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: - Temperature (T <sub>L</sub> ) - Time (t <sub>L</sub> )	183°C 60-150 seconds	217°C 60-150 seconds
Peak/Classification Temperature (Tp)	See table 1	See table 2
Time within 5°C of actual Peak Temperature (tp)	10-30 seconds	20-40 seconds
Ramp-down Rate	6°C/second max.	6°C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

Note: All temperatures refer to topside of the package. Measured on the body surface.

Table 1. SnPb Eutectic Process – Package Peak Reflow Temperatures

Package Thickness	Volume mm <sup>3</sup> <350	Volume mm³ ³350
<2.5 mm	240 +0/-5°C	225 +0/-5°C
≥2.5 mm	225 +0/-5°C	225 +0/-5°C

Table 2. Pb-free Process – Package Classification Reflow Temperatures

Package Thickness	Volume mm <sup>3</sup> <350	Volume mm <sup>3</sup> 350-2000	Volume mm <sup>3</sup> >2000
<1.6 mm	260 +0°C*	260 +0°C*	260 +0°C*
1.6 mm – 2.5 mm	260 +0°C*	250 +0°C*	245 +0°C*
≥2.5 mm	250 +0°C*	245 +0°C*	245 +0°C*

<sup>\*</sup> Tolerance: The device manufacturer/supplier **shall** assure process compatibility up to and including the stated classification temperature (this means Peak reflow temperature +0°C. For example 260°C+0°C) at the rated MSL level.

#### **Customer Service**

#### **Anpec Electronics Corp.**

Head Office:

No.6, Dusing 1st Road, SBIP, Hsin-Chu, Taiwan, R.O.C. Tel: 886-3-5642000 Fax: 886-3-5642050

Taipei Branch:

2F, No. 11, Lane 218, Sec 2 Jhongsing Rd., Sindian City, Taipei County 23146, Taiwan

Tel: 886-2-2910-3838 Fax: 886-2-2917-3838